

REVISIONS			DOC. NO. SPC-F004 * Effective: 7/8/02 * DCP No: 1398					
DCP #	REV	DESCRIPTION	DRAWN	DATE	CHECKD	DATE	APPRVD	DATE
1262	Α	RELEASED	НО	12/27/02	LS	12/27/02	DJC	12/27/02
1885	В	UPDATED TO ROHS COMPLIANT	EO	02/04/06	НО	2/6/06	НО	2/6/06

Absolute Maximum Ratings:

- Collector-Base Voltage, $\bar{V}_{CBO} = 180V$
- Collector-Emitter Voltage, V_{CEO} = 160V
- Emitter-Base Voltage, $V_{EBO} = 6V$
- Continuous Collector Current, $I_C=600 \text{mA}$ Total Device Dissipation ($T_A=+25^{\circ}\text{C}$), $P_D=625 \text{mW}$

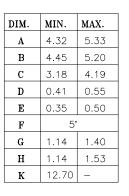
Derate above $25^{\circ}C = 5 \text{mW/}^{\circ}C$

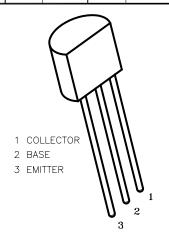
- Total Device Dissipation (T_C = +25°C), P_D = 1.5W Derate above 25°C = 12mW/°C

- Operating Junction Temperature Range, $T_J = -55^{\circ}\text{C} \sim +150^{\circ}\text{C}$ Storage Temperature Range, $T_{stg} = -55^{\circ}\text{C} \sim +150^{\circ}\text{C}$ Thermal Resistance, Junction to Case, $R_{thJC} = 83.3^{\circ}\text{C/W}$

- Thermal Resistance, Junction to Ambient (Note 1), $R_{thJA} = 200^{\circ}C/W$

Electrical Characteristics: $(T_A = +25^{\circ}C)$ unless otherwisze specified)





Parameter	Symbol	Test Conditions	Min	Max	Unit		
OFF Characteristics							
Collector—Base Breakdown Voltage	V _{(BR)CB0}	$I_{\mathbf{C}} = 100 \mu A, \ I_{\mathbf{E}} = 0$	180	_	V		
0 II I E III B II VIII	17	T 40 A T 0 N L 0	4.00				

RoHS

Compliant

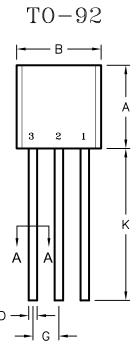
Collector—Base Breakdown Voltage	V(BR)CBO	$I_{\mathbf{C}} = 100\mu A, I_{\mathbf{E}} = 0$	100	_	ľ
Collector—Emitter Breakdown Voltage	V _{(BR)CEO}	I_C = 1.0mA, I_B = 0, Note 2	160	_	V
Emitter—Base Breakdown Voltage	V _{(BR)EBO}	$I_{\rm E}$ = 10 μ A, $I_{\rm C}$ = 0	6	_	٧
Collector Cut-Off Current	I _{CBO}	$V_{CB} = 120V, I_{E} = 0$	_	50	nA
		$V_{CB} = 120V, I_{E} = 0, T_{A} = +100^{\circ}C$	_	50	uA
Emitter Cut-Off Current	I _{EBO}	$V_{EB} = 4V, I_{C} = 0$	-	50	nA

ON Characteristics (Note 2)

DC Current Gain	h _{FE}	$V_{CE} = 5V$, $I_{C} = 1.0$ mA	80	-	-
		$V_{CE} = 5V$, $I_{C} = 10$ mA	80	250	-
		$V_{CE} = 5V$, $I_{C} = 50$ mA	30	-	-
Collector—Emitter Saturation Voltage	V _{CE(sat)}	$I_{\rm C}$ = 10mA, $I_{\rm B}$ = 1.0mA	_	0.15	V
		$I_{\rm C}=$ 50mA, $I_{\rm B}=$ 5.0mA	_	0.2	٧
Base—Emitter Saturation Voltage	V BE(sat)	$I_{\rm C}$ = 10mA, $I_{\rm B}$ = 1.0mA	_	1	٧
		$I_C = 50$ mA, $I_B = 5.0$ mA	_	1	V

Small-Signal Characteristics

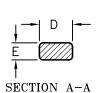
Current Gain-Bandwidth Product	f _T	V_{CE} = 10V, I_{C} = 10mA, f = 100MHz	100	300	MHz
Output Capacitance	C _{obo}	$V_{CB} = 10V$, $I_{E} = 0$, $f = 1MHz$	_	6	рF
Input Capacitance	C _{ibo}	$V_{BE} = 0.5V$, $I_{C} = 0$, $f = 1MHz$	_	20	рF
Small—Signal Current Gain	h _{fe}	V_{CE} = 10V, I_{C} = 1mA, f = 1kHz	50	200	_
Noise Figure	NF	$V_{CE} = 5V$, $I_C = 250\mu$ A, $f = 1$ kHz $R_S = 1$ kOhm	-	8	dB

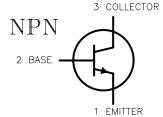


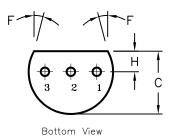
Notes:

1- R_{thJA} is measured with the device soldered into a typical printed circuit board.

2- Pulse Test: Pulse Width = 300 µs, Duty Cycle = 2%.







SPC-F004.DWG

TOLERANCES:	DRAWN BY:	DATE:		
UNLESS OTHERWISE	HISHAM ODISH	12/27/02		
SPECIFIED,	CHECKED BY:	DATE:		
DIMENSIONS ARE	LUIS SERBIA	12/27/02		
FOR REFERENCE PURPOSES ONLY.	APPROVED BY:	DATE:		
	DANIEL CAREY	12/27/02		

DRAWING TITLE: TRANSISTOR, BIPOLAR, TO-92, NPN

SIZE DWG. NO. 2N5551 SCALE: NTS

U.O.M.: MILLIMETERS

ELECTRONIC FILE 35C0727.DWG

SHEET:

REV

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